

## **I INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

## **MMD60R360P**

## • FEATURES

- Static drain-source on-resistance:  $R_{DS}(on) \leqslant 0.38 \Omega$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

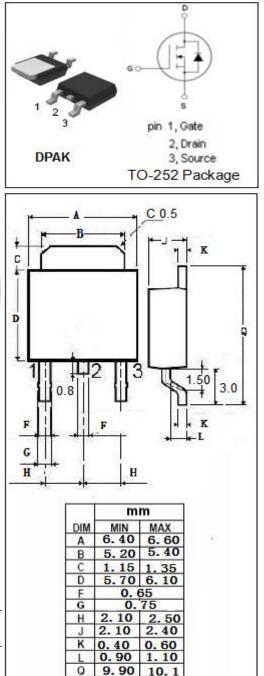
Switching applications

## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	600	v	
V <sub>GS</sub>	Gate-Source Voltage	±30	V	
ID	Drain Current-Continuous	11	A	
I <sub>DM</sub>	Drain Current-Single Pulsed	33	A	
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25°C	83	W	
Tj	Max. Operating Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature	-55~150	°C	
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# • THERMAL CHARACTERISTICS SYMBOL PARAMETER MAX UNIT Rth(j-c) Channel-to-case thermal resistance 1.5 °C/W

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### ELECTRICAL CHARACTERISTICS

 $T_c=25^{\circ}C$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =250 μ A	600			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =250 μ A	2		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =3.8A			0.38	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±30V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 600V; V <sub>GS</sub> = 0V			1	μA
Vsd	Diode forward voltage	Isd= 11A, V <sub>GS</sub> = 0V			1.4	V

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